



PCMC (Pure Copper Metallised Ceramic) package for high power application

S. Libon

Thales Alenia Space ETCA

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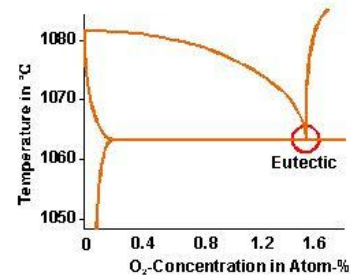
PCMC technology

Ceramic to Cu joint

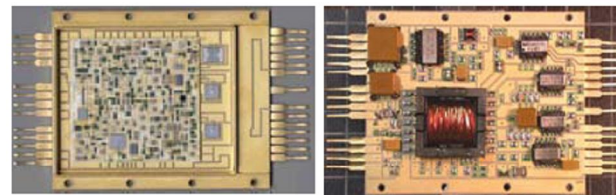
Interconnection (upper-lower level)

PCMC packages

Curamik DBC (Direct Bonded Copper)

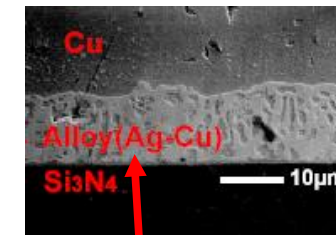


Spinell reaction of eutectic with alumina: $CuO + Al_2O_3 = CuAl_2O_4$

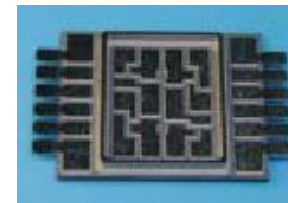
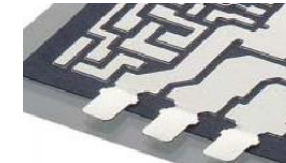
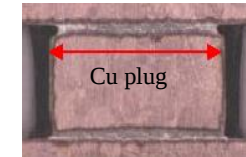


Supplier: Sagem electronics

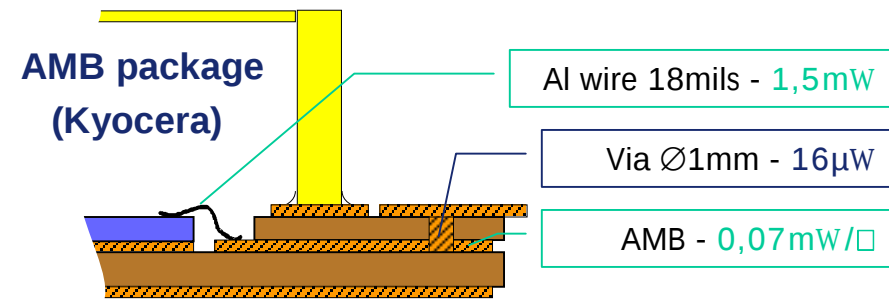
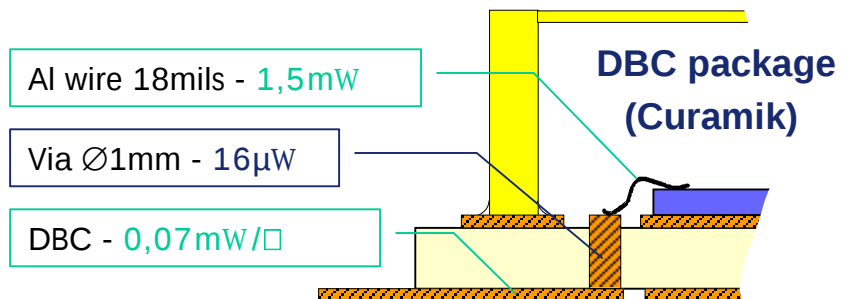
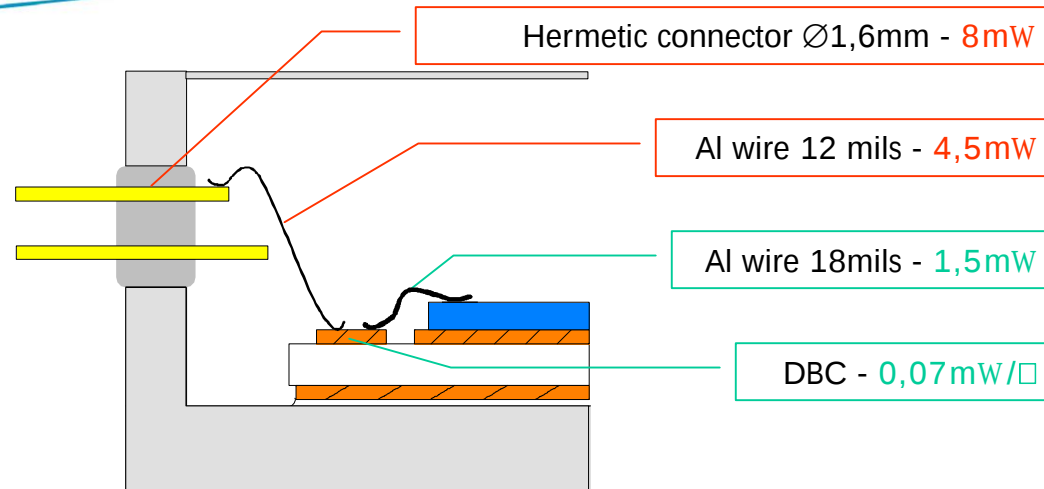
Kyocera AMB (Active Metal Brazing)



Ti
compound

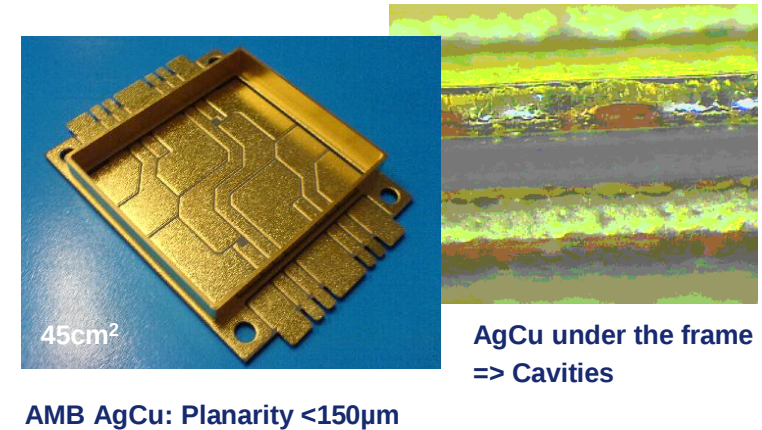
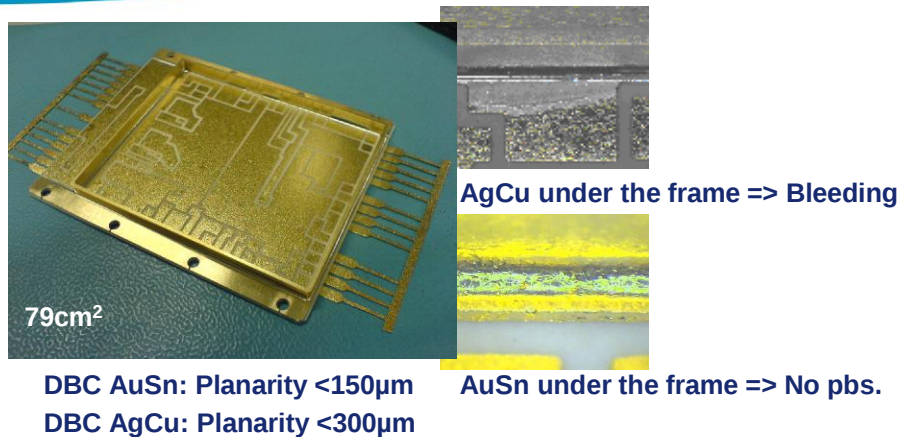


Actual solution (Homemade MCPH)

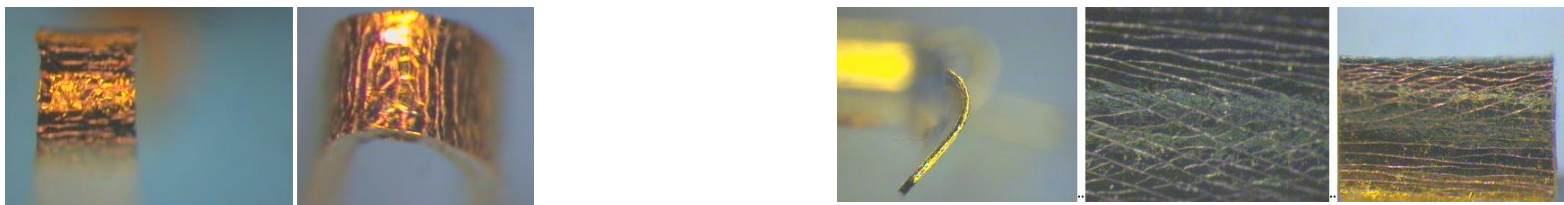


Reduction of serial resistance by a factor of 5

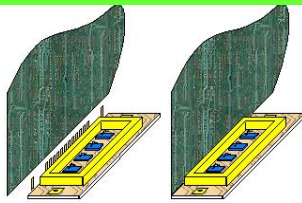
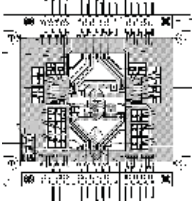
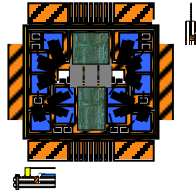
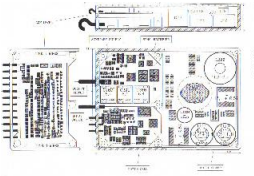
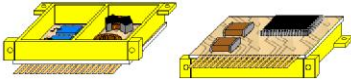
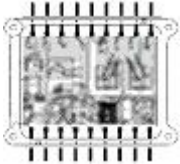
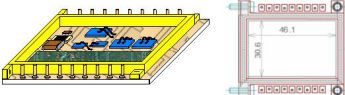
Material	Thermal conductivity (W/mK)	Flexural strength (MPa)	TCE (ppm/K)
Al ₂ O ₃	30	275	7,1
Si ₃ N ₄	60	850	2,7



1. Planarity will be a central issue
2. Better brazing capability with Curamik AuSn

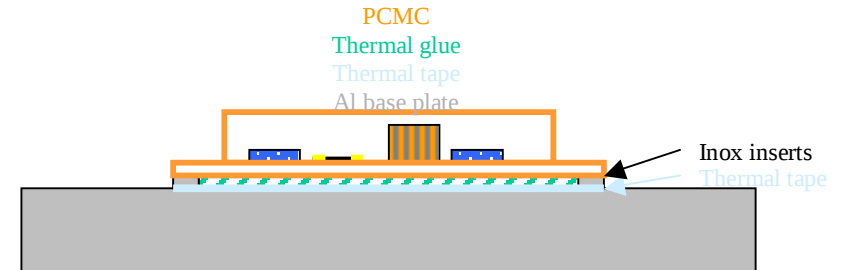
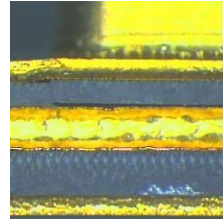
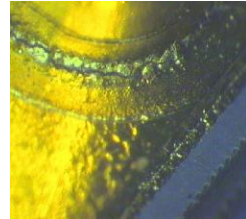
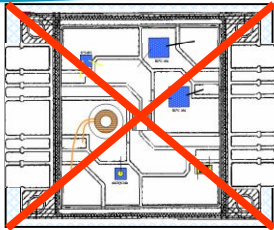


- Similar performances on
3. Ni/Au treatment resilience to bending
 4. Wire bonding capability (1 mil unsafe)

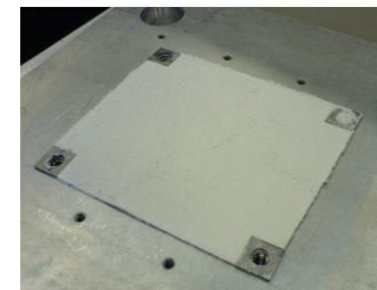
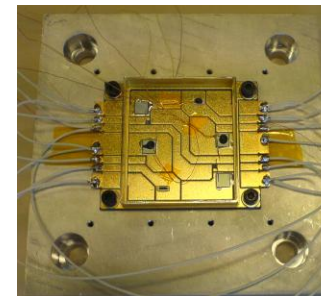
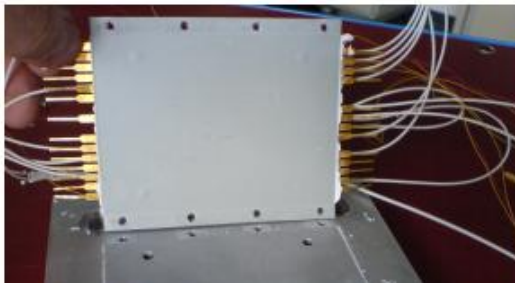
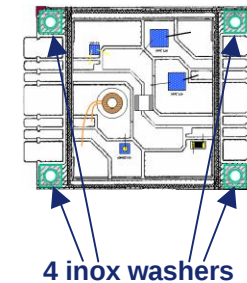
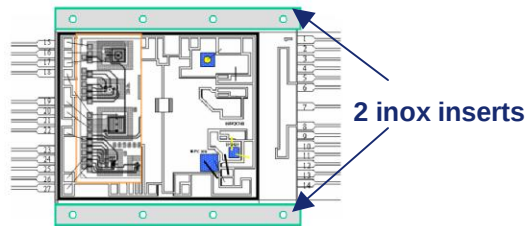
Application	Characteristics	Actual design	New design	Improvements
PCU	2,25kW transmitted 90W 17W/die diss. 100V 22,5A			- Trench height: & width - Volume: 7% - Weight: 40 to 50% - Cost: 8% - Electrical: 8W
HPPU inverter	3kW transmitted 36,8W 3W/die diss. (extreme: 15W/die) 1000V 45A			- Double Power capacity - Volume: 80% - Weight: 20% - Cost: 80% - Electrical: 24W
MPLC DC-DC converter	210W transmitted 15W 4W/die diss. 100V 18A			- Base plate real estate: 50% - Volume: 15% - Weight: >0 - Cost: 15% - Electrical: 10,5W
EPC SMART	500W transmitted 13W 4,4W/die diss. 200V 8A			- Double sided - Volume: 20% - Weight: 5% - Cost: 23% - Electrical: 0,6W

1 sided solution

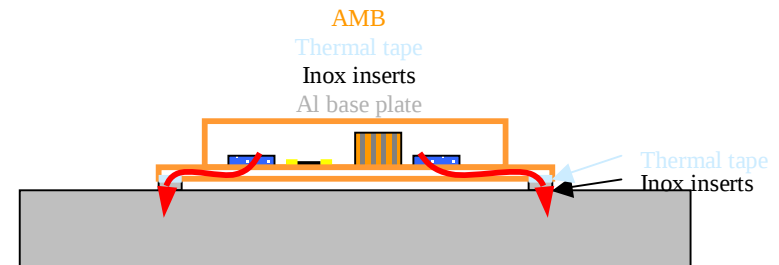
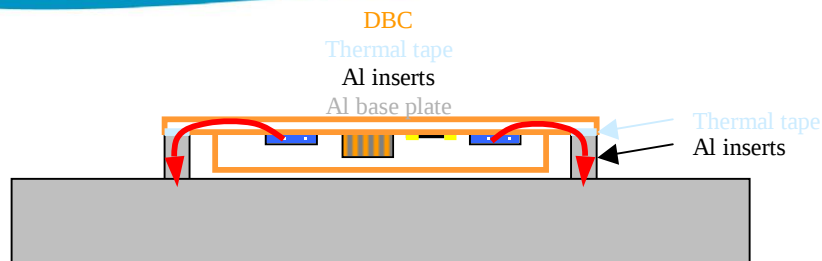
2 sided solution



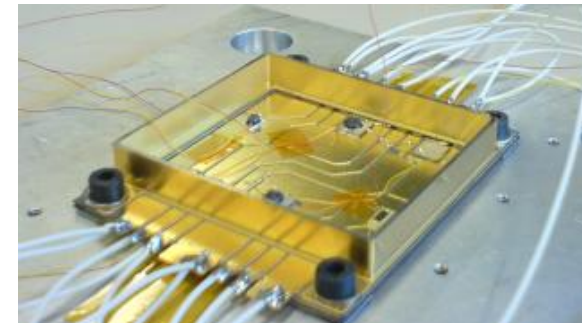
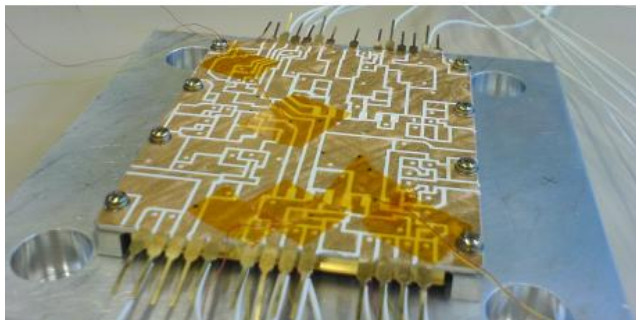
Mounting flat on a tape ⇨ Cracks under the frame (AMB) ⇨ Thermal glue with inox inserts



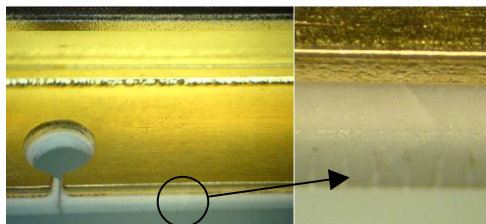
Reworkable; Base plate ready; Planarity in manufacturing (TBD)



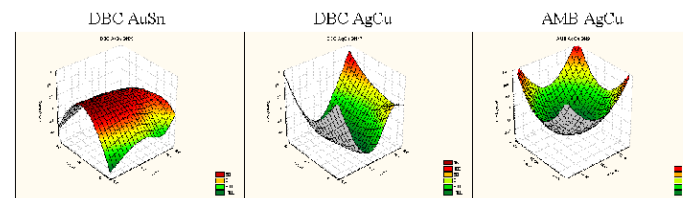
Thermal path trough mechanical structure



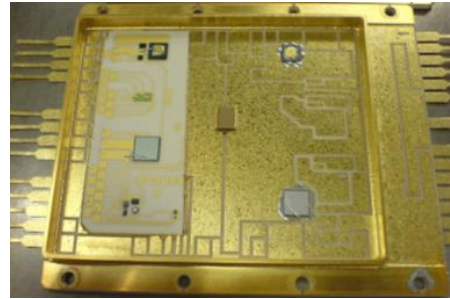
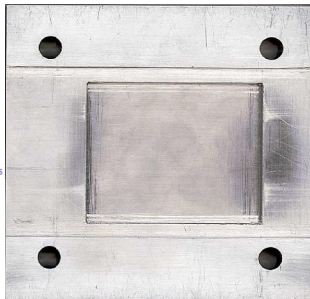
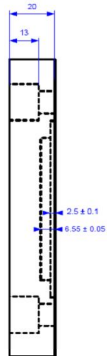
Inserts to represent the 2 sided fixture



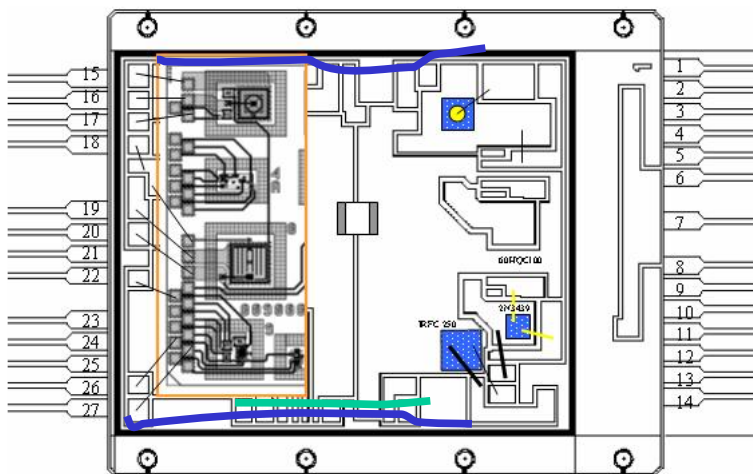
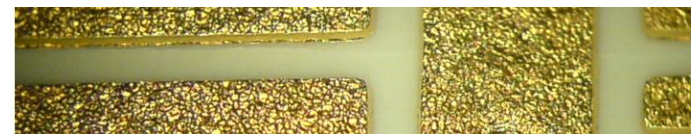
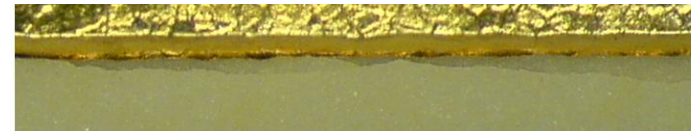
Stress at fixture points (DBC)



Cost to obtain co-planarity of fixture points



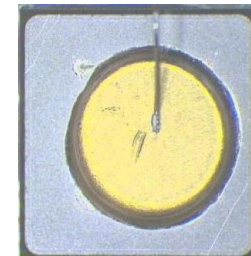
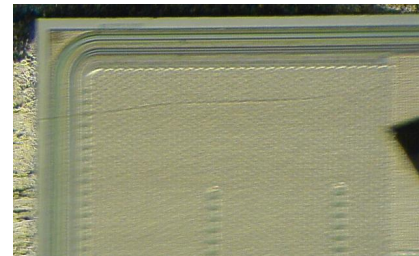
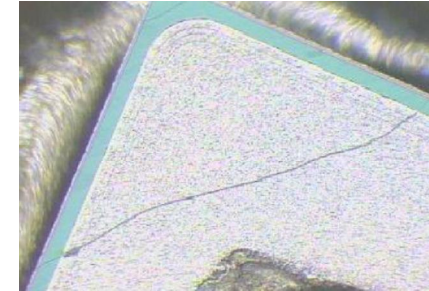
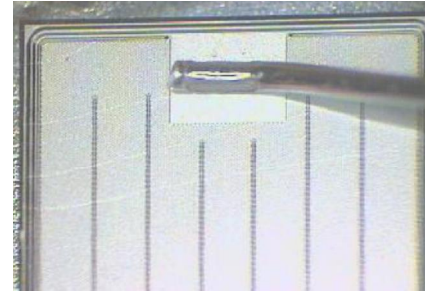
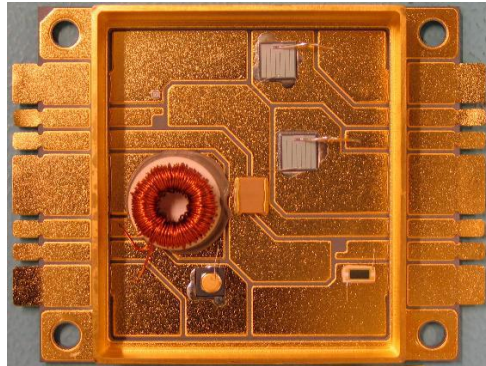
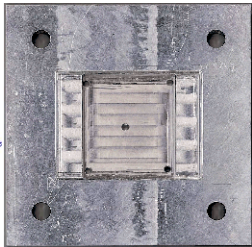
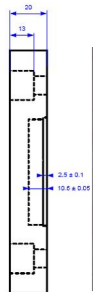
Perpendicular shocks fractures:



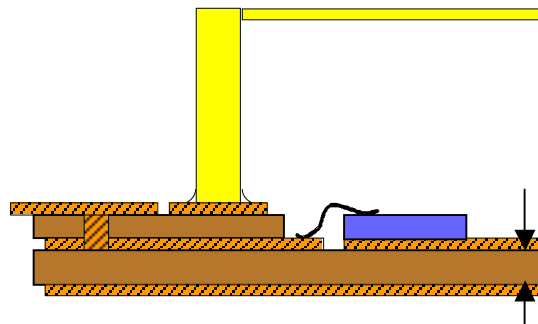
2000g AgCu

3000g AuSn

No problems with brazed components



Cracks on brazed components starting at 1500g perpendicular to package



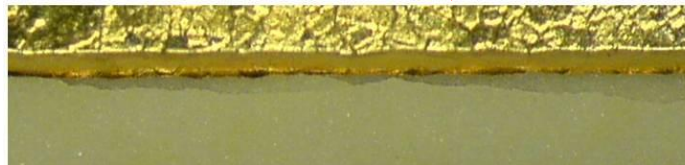
No problems on glued components or lateral chocks up to 2500G

625μm of Si₃N₄

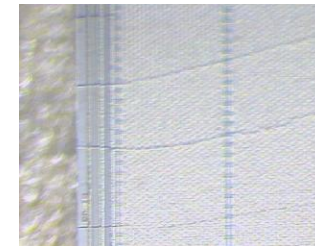
Ceramic materials characteristics (from Kyocera)

		Thermal Conductivity (W/m·K)	Flexural Strength (MPa)	Fracture Toughness (MPa ^{1/2})	CTE (ppm/degree-C)
DBC	96%Al ₂ O ₃	20	274	3.7	7.1
AMB	Si ₃ N ₄	60	700	6.5	2.7

Young modulus (GPa)	PCMC Thickness (μm)
@ 350	1000
@ 250	635



DBC AgCu @ 2000g
DBC AuSn @ 3000g
AMB pass 2500g

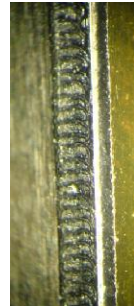
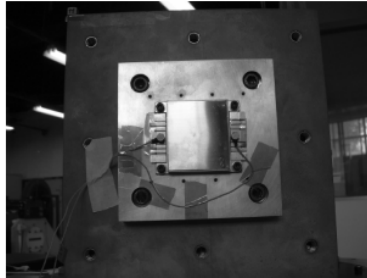


AMB @ 1500g
DBC AgCu pass 2000g

Conclusions:

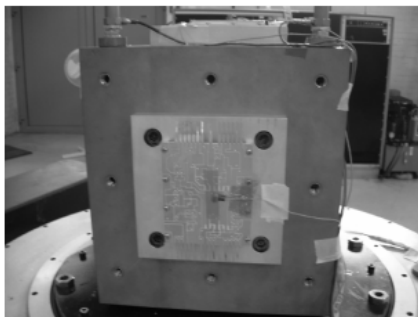
- 625μm Si₃N₄ unfit for brazed components → back reinforcement
- **→ brazed components not possible on 2-sided AMB packages**
- Al₂O₃ is intrinsically more fragile

Double-sided AMB

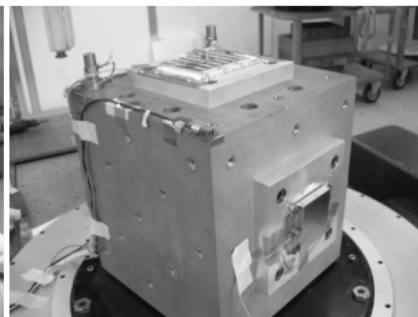


SN8 cover fracture during Y random vibrations due to a cover design error
=> Once repaired, no problem

DBC 2-sided

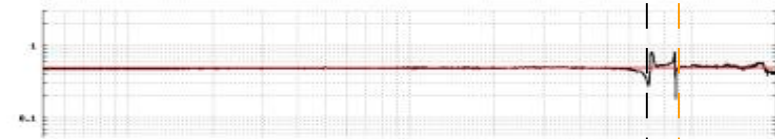


DBC 1-sided

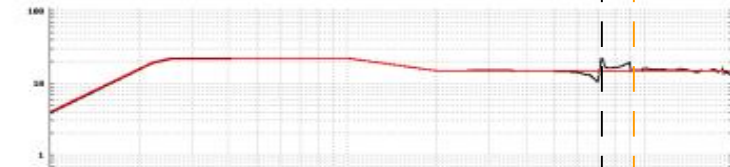


No problems, DBC 2-sided pushed up to 1.5 g²/Hz

**Reference
sin survey**



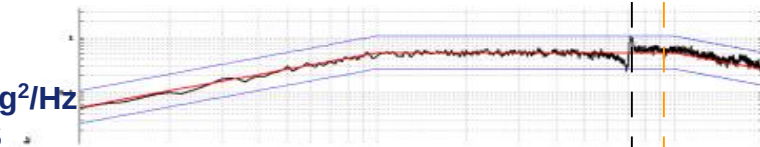
**High sinus
Peak@22.5g
1 oct/min**



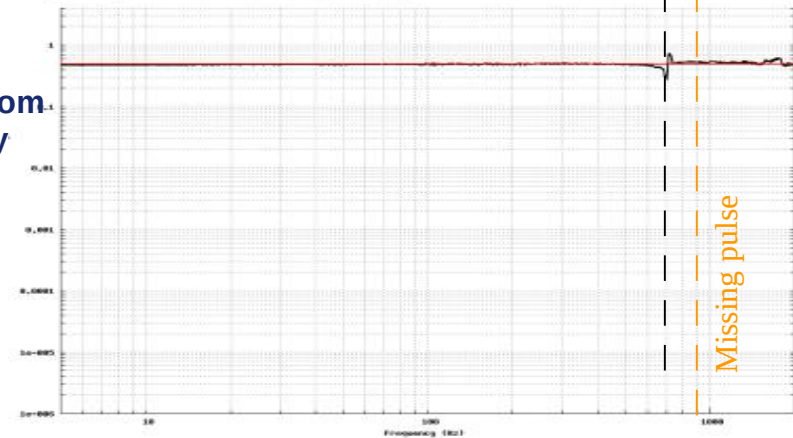
**Post-high sin
Sin survey**



**Random
peak @0.53 g²/Hz
29.53 g RMS
10 min**

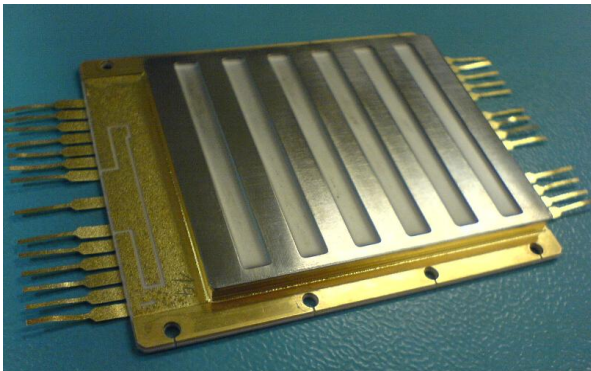


**Post-random
Sin survey**



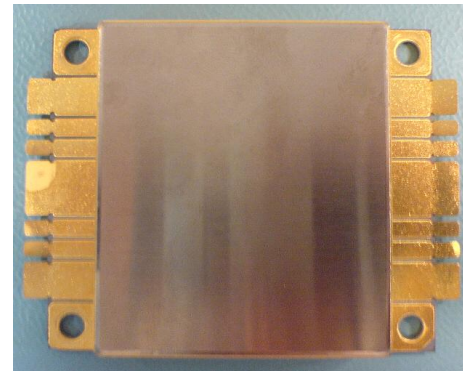
Thermal cycle:-55/+125°C in less than a minute

DBC



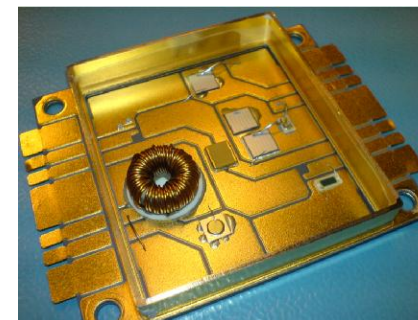
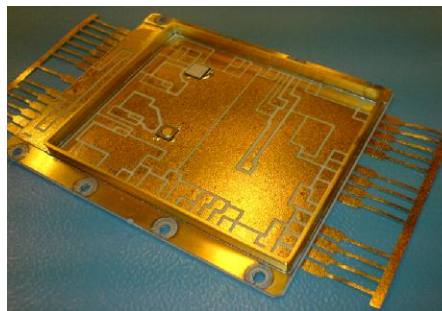
OK up to 500 cycles

AMB



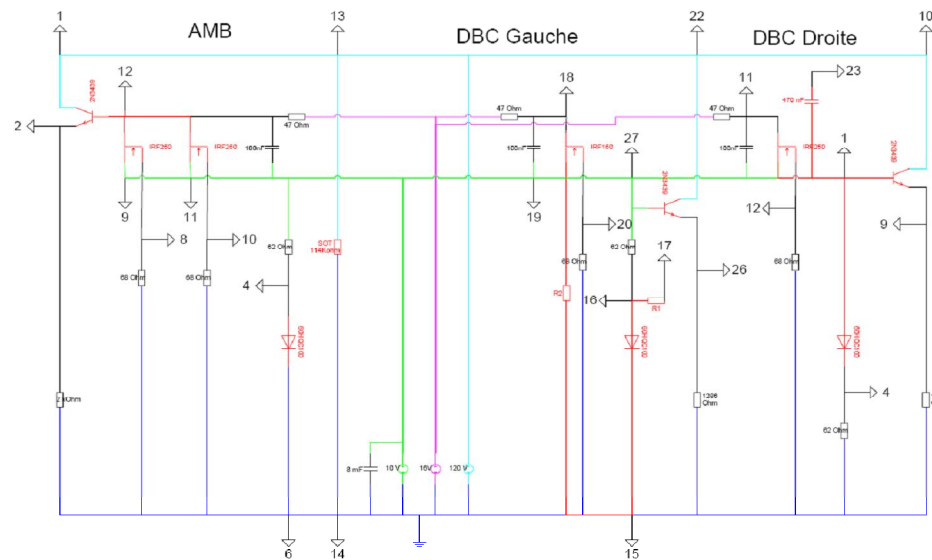
OK up to 500 cycles

	DBC SN14	AMB SN8	units
Pressure	652	721	torr
Nitrogen	79,2	79,9	%
Oxygen	4099	ND	ppm
Argon	336	<100	ppm
CO2	484	774	ppm
Moisture	6922	1349	ppm
Hydrogen	337	277	ppm
Helium	19,6	19,8	%
Fluorocarbon	<100	119	ppm
Hydrocarbon	<100	<100	ppm
O2/Ar	12,2		



Parylene deposition shows no problem

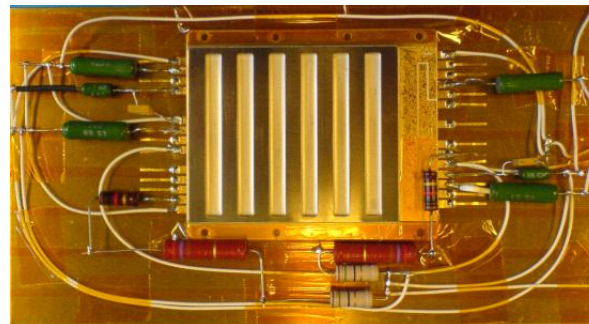
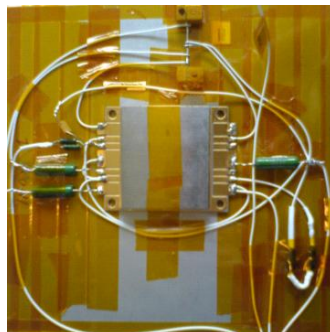
RGA Air trapped inside DBC:
Due to a processing error (air entrapment)

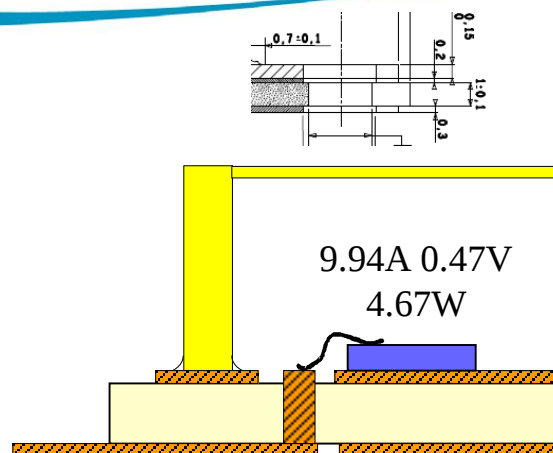


Following ESCC component specifications: 2000h 125°C

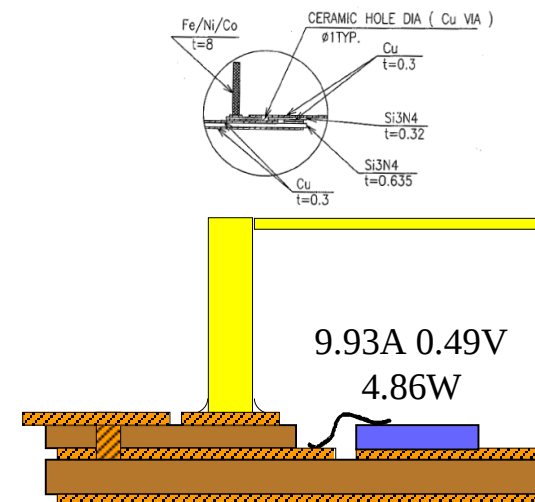
No significant change on:

- IRFC150
- IRFC250
- 2N3439
- 60HQC100
- ceramic capacitor
- thick film resistors
- Cu interconnections (for magnetics)





	K_{th}	Surface	Thickness	ΔT°
Si	150	$(6528\mu m)^2$	500 μm	0.35°
AuSn	253	$(6528\mu m)^2$	30 μm	0.01°
Cu	397	$(6528\mu m)^2$	200 μm	0.05°
Al_2O_3	30	$(6528\mu m)^2$	1000 μm	3.54°
Cu	397	$(6528\mu m)^2$	300 μm	0.08°
Total				4.04°
Measured				3.5°



	K_{th}	Surface	Thickness	ΔT°
Si	150	$(6528\mu m)^2$	500 μm	0.37°
AuSn	253	$(6528\mu m)^2$	30 μm	0.01°
Cu	397	$(6528\mu m)^2$	300 μm	0.08°
Si₃N₄	60	$(6528\mu m)^2$	635μm	1.17°
Cu	397	$(6528\mu m)^2$	300 μm	0.08°
Total				1.72°
Measured				2°

Uniaxial Results close to theoretical values
Cu tracks DT° neglectable vs ceramic

Problems encountered	AMB AgCu	DBC AgCu	DBC AuSn	Criticality
Cavities in brazing joint	3/10 opposing cavities			Aspect
Ni/Au cracks during lead bending	Always	Always	Always	Aspect
Planarity	<150µm (45cm ²)	<300µm (80cm ²)	<150µm (80cm ²)	Fabricability
Substrate flexibility	OK up to 45cm ² No brazed component allowed >1000g	OK up to 80cm ² Brazed components	OK up to 80cm ² No brazed component	Capability
Chock resilience	>2500g	>1500g	>2500g	Yield
Thermal transfer	60 W/mK	30 W/mK	30 W/mK	Capability

Final choice:
 -Limited risk
 -Large substrates
 -No brazed components